NSN 5961-01-341-3323

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-341-3323 **Inclosure Material:** Glass **Overall Length:** Between 4.8 millimeters and 5.2 millimeters **Overall Diameter:** Between 2.39 millimeters and 2.66 millimeters **Function For Which Designed:** Voltage reference Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-213ab **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 5.1 regulator voltage **Voltage Tolerance In Percent:** -10.0/+10.0 **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector absolute **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: